

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	435	257/10 and (emit\$5)	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/21 14:30
L2	14	("4772489" "5242538" "5385862" "5805624" "5904860" "5948161" "5985747" "6008502" "6045978" "6046088" "6080529" "6096592" "6171917" "6265287").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/21 13:31
L3	5	("5691608").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/21 13:31
L4	13	("3449620" "3579015" "3720859" "3845243" "3863023" "4067047" "4259678" "4303930" "4325084" "4361781" "4368467" "4701811").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/21 13:34
L5	0	("5691608").URPN.	USPAT	OR	ON	2005/04/21 13:34
L6	25	microdischarge and (cavity) and (semiconductor or (n-type) or (p-type))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 14:35
L7	2	("3793552" "6695664").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/21 14:33
L8	56420	(cavity) and (semiconductor or (n-type) or (p-type))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 14:35
L9	2897	(cavity with (taper\$3 or narrow\$4)) and (semiconductor or (n-type) or (p-type))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 14:35
L10	948	(cavity with (taper\$3 or narrow\$4)) and (semiconductor or (n-type) or (p-type)) and (electron)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 14:36
L11	716	(cavity with (taper\$3 or narrow\$4)) and (semiconductor or (n-type) or (p-type)) and (electron) and (insulat\$4 or dielectric)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 15:16

L12	2	("6147349").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/21 15:16
S1	0	(method and (manufactur\$4 or fabricat\$4) and dishcharge).ti. and cavity and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 08:20
S2	4154	(method and (manufactur\$4 or fabricat\$4)).ti. and cavity and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/09/15 13:32
S3	3	(method and (manufactur\$4 or fabricat\$4) and discharge).ti. and cavity and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/09/15 13:33
S4	45	(method and (manufactur\$4 or fabricat\$4) and discharge).ti. and cavity	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/09/15 13:37
S5	328	(method and (manufactur\$4 or fabricat\$4) and discharge).ti. and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/09/15 13:37
S6	12	"445"/\$ and (method and (manufactur\$4 or fabricat\$4) and discharge).ti. and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/09/15 13:39
S7	117	(cavity with etch\$4 with (n-type or p-type)) and semiconductor	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 14:31
S8	4	(cavity with etch\$4 with (n-type or p-type)) and semiconductor and lamp	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/09/15 13:40
S9	2	("6016027").PN.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT	OR	OFF	2004/09/15 13:57
S10	19	313/356 and (semiconductor)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 08:27
S11	2	("6016027").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/19 08:21

S12	2	("5686789").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/19 08:21
S13	2	("6139384").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/19 08:22
S14	2	("6082294").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/19 08:22
S15	2	("5939829").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/19 08:22
S16	934	313/356	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 08:27
S17	25	313/356 and (semiconductor or silicone or Si)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 10:50
S18	39	313/356 and (semiconductor or silicone or Si or silicon)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 08:40
S19	2	("5387805").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2004/11/19 08:33
S20	14	("4110775" "4672624" "5013902" "5055979" "5062116" "5200973" "5387805" "5686789" "5939829" "6016027" "6082294" "6139384" "6353289" "6563257").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2004/11/19 08:34
S21	39	313/356 and (semiconductor or silicone or Si or silicon or p-type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 08:42
S22	40	313/618 and (semiconductor or silicone or Si or silicon or p-type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 08:46
S23	199	313/631 and (semiconductor or silicone or Si or silicon or p-type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 09:14

S24	95	313/632 and (semiconductor or silicone or Si or silicon or p-type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 09:19
S25	578	313/498 and (semiconductor or silicone or Si or silicon or p-type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 10:45
S26	67	313/567 and (semiconductor or silicone or Si or silicon or p-type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 10:50
S27	73	313/574 and (semiconductor or silicone or Si or silicon or p-type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 10:56
S28	437	257/12 and (semiconductor or silicone or Si or silicon or p-type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 11:38
S29	423	257/656 and (semiconductor or silicone or Si or silicon or p-type or n-type)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2004/11/19 13:38
S30	18	"6016027"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/07 10:31
S31	5	"5691608"	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/07 10:34
S32	1	"313"/\$ and (restricted near getter).ti.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/07 10:35
S33	6	("5686789" "5939829" "6082294" "6139384" "6194833" "6346770").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/07 10:43
S34	14	("4110775" "4672624" "5013902" "5055979" "5062116" "5200973" "5387805" "5686789" "5939829" "6016027" "6082294" "6139384" "6353289" "6563257").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/07 10:43
S35	5	("5686789" "5939829" "6016027" "6082294" "6139384").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/07 10:48

S36	5	("5185552" "5327475" "5499282" "6016027" "6031241").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/07 10:49
S37	19	("3487254" "3697797" "3908147" "3970887" "4060748" "4459636" "4698546" "4808883" "4890031" "4988918" "5438343" "5496199" "5514847" "5926496" "5990620" "6016027" "6139384" "6194833").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/07 10:49
S38	15	("3487254" "3697797" "3908147" "3970887" "4060748" "4698546" "4808883" "4890031" "4988918" "5438343" "5496199" "5514847" "5926496" "5990620").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/07 10:52
S39	12	("3487254" "3697797" "3908147" "3970887" "4060748" "4808883" "4890031" "4988918" "5438343" "5496199" "5514847").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/07 10:53
S40	160	372/87 and (semiconductor or silicone or Si)	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 10:46
S41	26	313/356 and (semiconductor or silicone or Si or (n-type) or (p-type))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 10:51
S42	27	313/618 and (semiconductor or silicone or Si or (n-type) or (p-type))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 10:51
S43	161	372/87 and (semiconductor or silicone or Si or (n-type) or (p-type))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 10:54
S44	379	438/20 and (semiconductor or silicone or Si or (n-type) or (p-type))	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	ON	2005/04/21 10:54
S45	2	("5387805").PN.	US-PGPUB; USPAT; EPO; JPO; DERWENT	OR	OFF	2005/04/21 10:54

S46	2	("4502070" "5202750").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/21 10:55
S47	2	("4717940" "5034785").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/21 10:55
S48	30	("5202750").URPN.	USPAT	OR	ON	2005/04/21 10:56
S49	26	("4048649" "4329705" "4725562" "4799095" "4945394" "4981551" "5014102" "5087576" "5168331" "5170231" "5202750" "5233215" "5264713" "5270554" "5304821" "5323040" "5331194" "5396085" "5459107" "5488236" "5489787" "5506421" "5539217" "5679966" "5719409" "5723891").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2005/04/21 13:19